# 74LVC2GU04-Q100

Dual inverter
Rev. 1 — 31 July 2012

**Product data sheet** 

#### 1. **General description**

The 74LVC2GU04 provides two inverters. Each inverter is a single stage with unbuffered output.

The inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of this device in a mixed 3.3 V and 5 V environment.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

#### **Features and benefits** 2.

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - ◆ Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range from 1.65 V to 5.5 V
- 5 V tolerant input/output for interfacing with 5 V logic
- High noise immunity
- ESD protection:
  - MIL-STD-883, method 3015 exceeds 2000 V
  - ♦ HBM JESD22-A114F exceeds 2000 V
  - ♦ MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- $\pm$  24 mA output drive (V<sub>CC</sub> = 3.0 V)
- CMOS low power consumption
- Latch-up performance exceeds 250 mA
- Input accepts voltages up to 5 V
- Multiple package options

#### 3. **Ordering information**

Table 1. **Ordering information** 

Type number	Package	ackage				
	Temperature range	Name	Description	Version		
74LVC2GU04GW-Q100	-40 °C to +125 °C	SC-88	plastic surface-mounted package; 6 leads	SOT363		
74LVC2GU04GV-Q100	–40 °C to +125 °C	TSOP6	plastic surface-mounted package (TSOP6); 6 leads	SOT457		



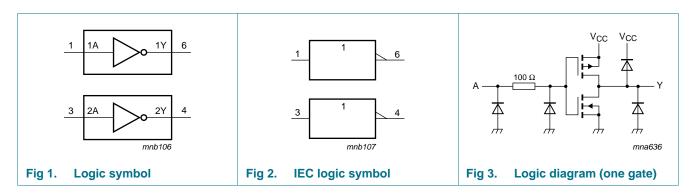
# 4. Marking

#### Table 2. Marking codes

Type number	Marking[1]
74LVC2GU04GW-Q100	YD
74LVC2GU04GV-Q100	VU4

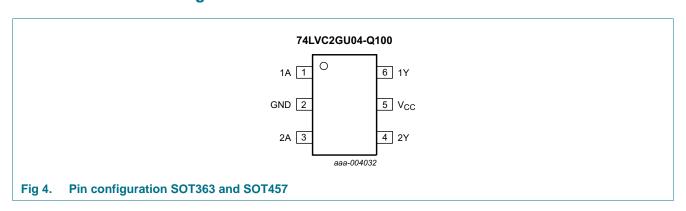
<sup>[1]</sup> The pin 1 indicator is located on the lower left corner of the device, below the marking code.

# 5. Functional diagram



# 6. Pinning information

### 6.1 Pinning



# 6.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
1A	1	data input
GND	2	ground (0 V)
2A	3	data input
2Y	4	data output
V <sub>CC</sub>	5	supply voltage
1Y	6	data output

# 7. Functional description

#### Table 4. Function table[1]

Input	Output
nA	nY
L	Н
Н	L

<sup>[1]</sup> H = HIGH voltage level; L = LOW voltage level.

# 8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		-0.5	+6.5	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V	-50	-	mA
VI	input voltage		<u>[1]</u> -0.5	+6.5	V
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < 0 V	-50	-	mA
Vo	output voltage	Active mode	[ <u>1][2]</u> -0.5	$V_{CC} + 0.5$	V
Io	output current	$V_O = 0 V \text{ to } V_{CC}$	-	±50	mA
I <sub>CC</sub>	supply current		-	100	mA
$I_{GND}$	ground current		-100	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +125  ^{\circ}\text{C}$	[3] _	250	mW

<sup>[1]</sup> The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>[2]</sup> When  $V_{CC} = 0 \text{ V}$  (Power-down mode), the output voltage can be 5.5 V in normal operation.

<sup>[3]</sup> For SC-88 and SC-74 packages: above 87.5  $^{\circ}$ C the value of P $_{tot}$  derates linearly with 4.0 mW/K.

# 9. Recommended operating conditions

Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CC}$	supply voltage		1.65	-	5.5	V
$V_{I}$	input voltage		0	-	5.5	V
$V_{O}$	output voltage	Active mode	0	-	$V_{CC}$	V
T <sub>amb</sub>	ambient temperature		-40	-	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	V <sub>CC</sub> = 1.65 V to 2.7 V	-	-	20	ns/V
		V <sub>CC</sub> = 2.7 V to 5.5 V	-	-	10	ns/V

# 10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = -	40 °C to +85 °C[1]					
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 1.65 V to 5.5 V	$0.75 \times V_{CC}$	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 1.65 V to 5.5 V	-	-	$0.25 \times V_{CC}$	V
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		$I_O = -100 \mu A;$ $V_{CC} = 1.65 \text{ V to } 5.5 \text{ V}$	V <sub>CC</sub> - 0.1	-	-	V
	$I_{O} = -4 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.2	-	-	V	
		$I_{O} = -8 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.9	-	-	V
		$I_{O} = -12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	2.2	-	-	V
		$I_{O} = -24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.3	-	-	V
		$I_{O} = -32 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.8	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		$I_O = 100 \mu A;$ $V_{CC} = 1.65 \text{ V to } 5.5 \text{ V}$	-	-	0.1	V
		$I_O = 4 \text{ mA}$ ; $V_{CC} = 1.65 \text{ V}$	-	-	0.45	V
		$I_{O} = 8 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.3	V
		$I_O = 12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	-	-	0.4	V
		$I_O = 24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.55	V
		$I_O = 32 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.55	V
I <sub>I</sub>	input leakage current	$V_I = 5.5 \text{ V or GND};$ $V_{CC} = 0 \text{ V to } 5.5 \text{ V}$	[2] _	±0.1	±5	μΑ
I <sub>CC</sub>	supply current	$V_I = 5.5 \text{ V or GND}; I_O = 0 \text{ A};$ $V_{CC} = 1.65 \text{ V to } 5.5 \text{ V}$	-	0.1	10	μΑ
Cı	input capacitance	$V_{CC}$ = 3.3 V; $V_I$ = GND to $V_{CC}$	-	5	-	pF

 Table 7.
 Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = -	40 °C to +125 °C					
$V_{IH}$	HIGH-level input voltage	V <sub>CC</sub> = 1.65 V to 5.5 V	$0.8 \times V_{CC}$	-	-	V
$V_{IL}$	LOW-level input voltage	V <sub>CC</sub> = 1.65 V to 5.5 V	-	-	$0.2 \times V_{CC}$	V
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
	$I_O = -100 \mu A;$ $V_{CC} = 1.65 \text{ V to } 5.5 \text{ V}$	V <sub>CC</sub> - 0.1	-	-	V	
	$I_{O} = -4 \text{ mA}; V_{CC} = 1.65 \text{ V}$	0.95	-	-	V	
	$I_{O} = -8 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.7	-	-	V	
		$I_{O} = -12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	1.9	-	-	V
		$I_{O} = -24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.0	-	-	V
		$I_{O} = -32 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.4	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		$I_O = 100 \mu A;$ $V_{CC} = 1.65 \text{ V to } 5.5 \text{ V}$	-	-	0.1	V
		$I_O = 4 \text{ mA}; V_{CC} = 1.65 \text{ V}$	-	-	0.7	V
		$I_O = 8 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.45	V
		$I_O = 12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	-	-	0.6	V
		$I_O = 24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.8	V
		$I_O = 32 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.8	V
lı	input leakage current	$V_I = 5.5 \text{ V or GND};$ $V_{CC} = 0 \text{ V to 5.5 V}$	-	-	±20	μΑ
I <sub>CC</sub>	supply current	$V_I = 5.5 \text{ V or GND}; I_O = 0 \text{ A};$ $V_{CC} = 1.65 \text{ V to } 5.5 \text{ V}$	-	-	40	μΑ

<sup>[1]</sup> All typical values are measured at  $T_{amb}$  = 25 °C.

<sup>[2]</sup> These typical values are measured at  $V_{CC}$  = 3.3 V.

# 11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V). For test circuit see Figure 6.

Symbol	Parameter	Conditions		-40 °C to +85 °C			-40 °C to +125 °C		Unit
				Min	Typ[1]	Max	Min	Max	
$t_{pd}$	propagation delay	nA to nY; see Figure 5	[2]						
	$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		0.5	2.3	5.0	0.5	6.3	ns	
	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.3	1.8	4.0	0.3	5.0	ns	
	V <sub>CC</sub> = 2.7 V		0.3	2.6	4.5	0.3	5.6	ns	
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		0.3	2.3	3.7	0.3	4.5	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		0.3	1.7	3.0	0.3	3.8	ns
$C_{PD}$	power dissipation capacitance	$V_I = GND \text{ to } V_{CC}; V_{CC} = 3.3 \text{ V}$	[3]	-	7.8	-			pF

- [1] Typical values are measured at  $T_{amb} = 25$  °C and  $V_{CC} = 1.8$  V, 2.5 V, 2.7 V, 3.3 V and 5.0 V respectively.
- [2]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .
- [3]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

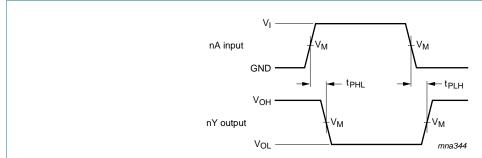
C<sub>L</sub> = output load capacitance in pF;

 $V_{CC}$  = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

#### 12. Waveforms



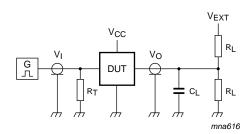
Measurement points are given in Table 9.

 $V_{\text{OL}}$  and  $V_{\text{OH}}$  are typical output voltage levels that occur with the output load.

Fig 5. The input (nA) to output (nY) propagation delay times

Table 9. Measurement points

Supply voltage	Input	Output
V <sub>CC</sub>	V <sub>M</sub>	V <sub>M</sub>
1.65 V to 1.95 V	$0.5 \times V_{CC}$	0.5 × V <sub>CC</sub>
2.3 V to 2.7 V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$
2.7 V	1.5 V	1.5 V
3.0 V to 3.6 V	1.5 V	1.5 V
4.5 V to 5.5 V	$0.5 \times V_{CC}$	0.5 × V <sub>CC</sub>



Test data is given in Table 10.

Definitions for test circuit:

R<sub>L</sub> = Load resistance.

 $C_L$  = Load capacitance including jig and probe capacitance.

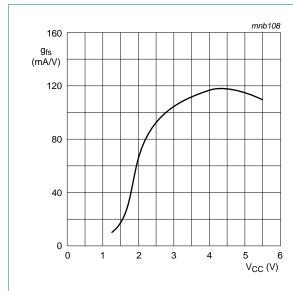
 $R_T$  = Termination resistance should be equal to the output impedance  $Z_0$  of the pulse generator.

 $V_{EXT}$  = External voltage for measuring switching times.

Fig 6. Test circuit for measuring switching times

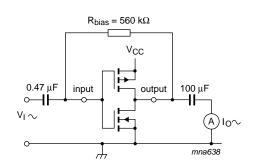
Table 10. Test data

Supply voltage	Input		Load		V <sub>EXT</sub>
V <sub>CC</sub>	V <sub>I</sub>	$t_r = t_f$	CL	R <sub>L</sub>	t <sub>PLH</sub> , t <sub>PHL</sub>
1.65 V to 1.95 V	V <sub>CC</sub>	≤ 2.0 ns	30 pF	1 kΩ	open
2.3 V to 2.7 V	V <sub>CC</sub>	≤ 2.0 ns	30 pF	500 Ω	open
2.7 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open
3.0 V to 3.6 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open
4.5 V to 5.5 V	V <sub>CC</sub>	≤ 2.5 ns	50 pF	500 Ω	open



 $T_{amb} = 25 \, ^{\circ}C.$ 

Fig 7. Typical forward transconductance as a function of supply voltage



$$g_{fs} = \frac{\Delta I_O}{\Delta V_I}$$

 $f_i = 1 \text{ kHz}.$ 

V<sub>O</sub> is constant.

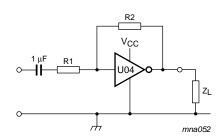
Fig 8. Test set-up for measuring forward transconductance

# 13. Application information

Some applications are:

- Linear amplifier (see Figure 9)
- Crystal oscillator design (see Figure 10)

Remark: All values given are typical unless otherwise specified.



 $V_{\text{O(p-p)}}$  =  $V_{\text{CC}}-1.5~\text{V}$  centered at  $0.5\times V_{\text{CC}}.$ 

$$A_u = -\frac{G_{OL}}{I + \frac{RI}{R2}(I + G_{OL})} \label{eq:au}$$

 $G_{OL}$  = open loop gain.

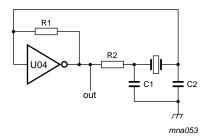
 $A_u$  = voltage amplification.

 $R1 \ge 3 \text{ k}\Omega, R2 \le 1 \text{ M}\Omega.$ 

 $Z_L > 10 \text{ k}\Omega$ ;  $A_{OL} = 20 \text{ (typical)}$ .

Typical unity gain bandwidth product is 5 MHz.

Fig 9. Linear amplifier configuration



C1 = 47 pF (typical).

C2 = 22 pF (typical).

R1 = 1 M $\Omega$  to 10 M $\Omega$  (typical).

R2 optimum value depends on the frequency and required stability against changes in  $V_{CC}$  or average minimum  $I_{CC}$  ( $I_{CC}$  is typically 2 mA at  $V_{CC}$  = 3.3 V and f = 10 MHz).

Fig 10. Crystal oscillator configuration

# 14. Package outline

#### Plastic surface-mounted package; 6 leads

**SOT363** 

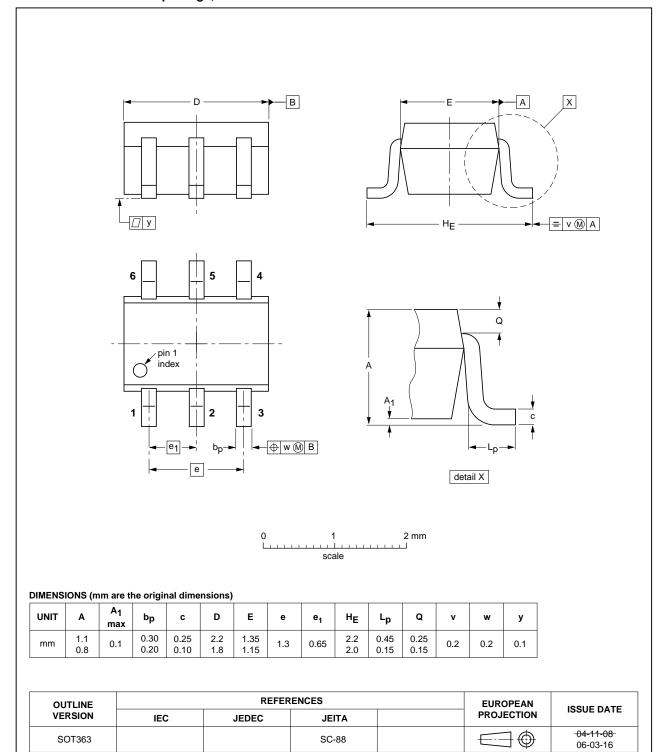


Fig 11. Package outline SOT363 (SC-88)

#### Plastic surface-mounted package (TSOP6); 6 leads

**SOT457** 

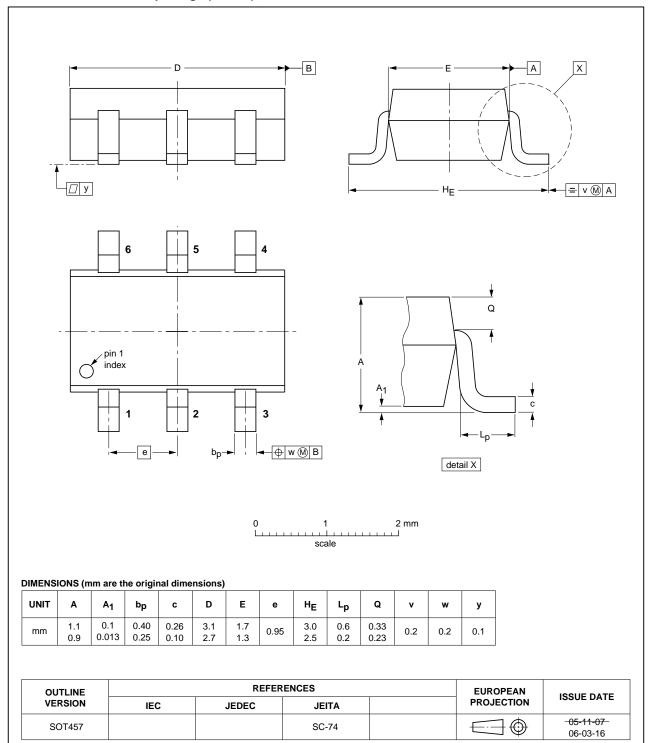


Fig 12. Package outline SOT457 (TSOP6)

# 15. Abbreviations

#### Table 11. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
MIL	Military

# 16. Revision history

#### Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LVC2GU04_Q100 v.1	20120731	Product data sheet	-	-

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### 17. Legal information

#### 17.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions"
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